



74HC595

8-BIT SHIFT REGISTER WITH 8-BIT OUTPUT REGISTER

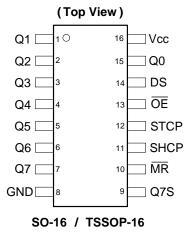
Description

The 74HC595 is an high speed CMOS device.

An eight bit shift register accpets data from the serial input (DS) on each positive transition of the shift register clock (SHCP). When asserted low the reset function ($\overline{\text{MR}}$) sets all shift register values to zero and is indepent of all clocks.

Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (STCP). With the output enable $(\overline{\text{OE}})$ asserted low the 3-state outputs Q0-Q7 become active and present th

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together the input shift register is always one clock cycle ahead of the output register.



Features

- Wide Supply Voltage Range from 2.0V to 6.0V
- Sinks or Sources 8mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- Inputs Accept up to 6.0V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Applications

General Purpose Logic

Pin Assignments

- Serial to Parallel Data Conversion
- Capture and Hold Data for Extended Periods of Time
- Allow Simple Serial Bit Streams from a Microcontroller to Control as Many Peripheral Lines as Needed
- Wide Array of Products such as:
 - Computer Peripherals
 - Appliances
 - Industrial Control

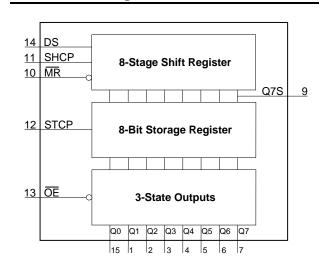
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



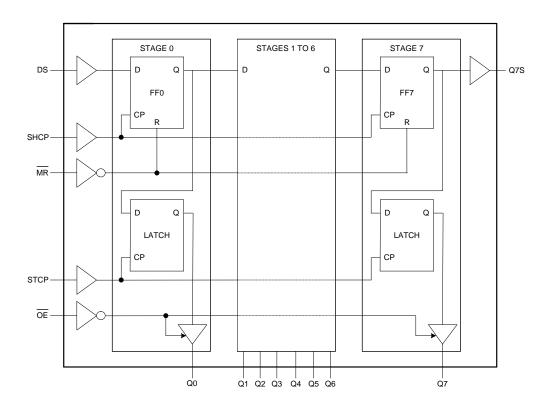
Pin Descriptions

Pin Number	Pin Name	Function				
1	Q1	Parallel Data Output 1				
2	Q2	Parallel Data Output 2				
3	Q3	Parallel Data Output 3				
4	Q4	Parallel Data Output 4				
5	Q5	Parallel Data Output 5				
6	Q6	Parallel Data Output 6				
7	Q7	Parallel Data Output 7				
8	GND	Ground				
9	Q7S	Serial Data Output				
10	MR	Master Reset Input				
11	SHCP	Shift Register Clock Input				
12	STCP	Storage Register Clock Input				
13	OE	Output Enable Input				
14	DS	Serial Data Input				
15	Q0	Parallel Data Output 0				
16	Vcc	Supply Voltage				

Functional Diagram



Logic Diagram





Functional Description and Timing Diagram

	Control		Input	Output		Evention		
SHCP	STCP	OE	MR	DS	Q7S	Qn	Function	
х	х	L	L	-	L	NC	Low-level asserted on MR clears shift register. Storage register is unchanged.	
Х	1	L	L	-	L	L	Empty shift register transferred to storage register.	
Х	Х	Н	L	-	L	Z	Shift register remains clear; All Q ouputs in Z state.	
¢	x	L	Н	-	Q6S	NC	HIGH is shifted into first stage of Shift Register Contents of each register shifted to next register. The content of Q6S has been shifted to Q7S and now appears on device pin Q7S.	
х	\uparrow	L	Н	_	NC	QnS	Contents of shift register copied to storage register. With output in active state the storage resister contents appear on Q outputs.	
\uparrow	\uparrow	L	Н	_	Q6S	QnS	Contents of shift register copied to output register then shift register shifted.	

H=HIGH Voltage State L=LOW Voltage State ↑=LOW to HIGH Transition X= Don'T Care – High or Low (Not Floating) NC= No Change Z= High-Impedance State

SHCP ⋠ 4 . 4 * DS STCP * 4 MR $\overline{\mathsf{OE}}$ Z-state Q0 Z-state Q1 Z-state Q6 Z-state Q7 Q7S



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Des	scription	Rating	Unit
ESD HBM	Human Body Model ESD Protection	on	2	kV
ESD CDM	Charged Device Model ESD Prote	ection	1	kV
ESD MM	Machine Model ESD Protection		200	V
V _{CC}	Supply Voltage Range		-0.5 to +7.0	V
VI	Input Voltage Range		-0.5 to +7.0	V
Vo	Voltage Applied to Output in High	or Low State	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current VI < -0.5V	1	-20	mA
lık	Input Clamp Current VI > VCC -	+0.5V	20	mA
I _{OK}	Output Clamp Current Vo < -0.5	V	-20	mA
I _{ОК}	Output Clamp Current V _O > V _{CC}	; +0.5V	20	mA
		Q7 Standard Output	±25	mA
lo	Continuous Output Current	Qn Bus Driver Outputs	±35	mA
lcc	Continuous Current through Vdd o	or GND	70	mA
I _{GND}	Continuous Current through Vdd o	or GND	-70	mA
TJ	Operating Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature		-65 to +150	°C
P _{TOT}	Total Power Dissipation		500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	-	2.0	6.0	V
VI	Input Voltage	-	0	Vcc	V
Vo	Output Voltage	Active Mode	0	V _{CC}	V
		$V_{CC} = 2.0V$	-	1000	ns/V
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 4.5V$	-	500	IIS/V
		$V_{CC} = 6.0V$	-	400	_
T _A	Operating Free-Air Temperature	-	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

0	Demonster	Test Conditions	v	т	_A = +25°(2	T _A = -40°C	to +85°C	T _A = -40°C	to +125°C	
Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Мах	Unit
		-	2.0V	1.5	1.2	-	1.5	-	1.5	-	
VIH	High-Level Input Voltage	-	4.5V	3.15	2.4	-	3.15	-	3.15	-	V
	input voltage	_	6.0V	4.2	3.2	-	4.2	-	4.2	-	
		-	2.0V	_	0.8	0.5	-	0.5	-	0.5	
VIL	Low-Level Input Voltage	-	4.5V	_	2.1	1.35	-	1.35	-	1.35	V
	input voltage	-	6.0V	-	2.8	1.8	-	1.8	-	1.8	
	High-Level		2.0V	1.9	2.0	-	1.9	-	1.9	-	
	Output	$I_{OH} = -20\mu A$	4.5V	4.4	4.5	-	4.4	-	4.4	-	
	Voltage	All Outputs	6.0V	5.9	6.0	-	5.9	-	5.9	-	
Vон	070 0 4 4	I _{OH} = -4.0mA	4.5V	3.84	4.32	-	4.32	-	3.7	-	V
	Q7S Output	I _{OH} = -5.2mA	6.0V	5.34	5.81	-	5.81	-	5.2	-	
	Qn Bus	I _{OH} = -6.0mA	4.5V	3.84	4.32	-	4.32	_	3.7	-	
	Outputs	I _{OH} = -7.8mA	6.0V	5.34	5.81	-	5.81	-	5.2	-	
	Low-Level Output		2.0V	-	0	0.1	-	0.1	-	0.1	
		I _{OL} = 20µA All Outputs	4.5V	_	0	0.1	-	0.1	-	0.1	
	Voltage	All Oulpuis	6.0V	_	0	0.1	-	0.1	-	0.1	
Vol	070 Output	$I_{OL} = 4.0 \text{mA}$	4.5V	_	.15	0.33	-	0.33	_	0.4	V
	Q7S Output	$I_{OL} = 5.2 \text{mA}$	6.0V	_	.16	0.33	-	0.33	-	0.4	
	Qn Bus	$I_{OL} = 6.0 \text{mA}$	4.5V	_	.15	0.33	-	0.33	-	0.4	
	Outputs	I _{OL} = 7.8mA	6.0V	_	.16	0.33	-	0.33	-	0.4	
l _l	Input Current	V _I =GND to 5.5V	6.0V	_	-	±0.1	-	± 1	-	± 1	μA
l _{oz}	OFF-State Output Current	Qn Internal High or Low Vo = V _{CC} or GND	6.0V	-	-	± 5	_	± 5	-	± 10	μA
I _{CC}	Supply Current	$V_{I} = GND \text{ or } V_{CC}$ $I_{O} = 0$	6.0V	_	_	8.0	_	80	-	160	μA
Ci	Input Capacitance	$V_1 = V_{CC}$ or GND	6.0V	_	4	10	_	10	-	10	pF

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

Parameter		Test Conditions	$V_{CC} = 5V$	Unit	
	i didilletei	Test conditions	Тур	onn	
C _{pd}	Power Dissipation Capacitance	f = 1 MHz All Outputs Switching-No Load	43	pF	

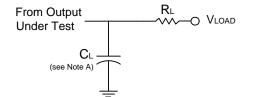


Switching Characteristics

Symbol /	Dime	Test Osmilitisms		-	Γ _A = +25°0	;	-40°C te	o +85°C	-40°C to	+125°C	11-14
Parameter	Pins	Test Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
f _{MAX}			2.0V	9	30	-	4.8	_	4	-	
Maximum	SHCP or STCP	Figure 1	4.5V	30	91	-	24	-	20	_	MHz
Frequency	5101		6.0V	35	108	-	28	_	24	-	
	SHCP		2.0V	75	17	_	95	_	110	_	
	HIGH or	Figure 1	4.5V	15	6	-	19	-	22	-	
	LOW		6.0V	13	5	-	16	_	19	_	
	STCP		2.0V	75	11	-	95	-	110	-	
t _W Pulse Width	HIGH or	Figure 1	4.5V	15	4	-	19	-	22	-	ns
Puise Width	LOW		6.0V	13	3	-	16	_	19	-	
			2.0V	75	17	-	95	_	110	-	
	MR LOW	Figure 1	4.5V	15	6	-	19	-	22	-	
			6.0V	13	5	-	16	-	19	-	
	50.		2.0V	50	11	-	65	-	75	-	
	DS to SHCP	Figure 1	4.5V	10	4	-	13	_	15	-	ns
ts∪	01101		6.0V	9	3	_	11	_	13	_	
Set-up Time			2.0V	75	22	-	95	_	110	-	
	SHCP tp STCP	Figure 1	4.5V	15	8	-	19	-	22	-	ns
	0101		6.0V	13	7	-	16	-	19	-	
	50.		2.0V	3	-6	-	3	-	3	-	
t _H Hold Time	DS to SHCP	Figure 1	4.5V	3	-2	_	3	_	3	_	ns
	01101		6.0V	3	-2	-	3	-	3	-	
_			2.0V	50	-19	_	65	_	75	_	
t _{REC} Recovery Time	MR to SHCP	Figure 1	4.5V	10	-7	-	13	_	15	-	ns
Recovery nine	51101		6.0V	9	-6	-	11	_	13	-	
		Figure 1	2.0V	-	52	160	-	200	-	240	
	SHCP to Q7S	Figure 1 C _L =50pF	4.5V	-	19	32	-	40	-	48	ns
t _{PD}	QIO	OL=30pi	6.0V	-	15	27	-	34	-	41	
Propagation Delay		Figure 1	2.0V	-	55	175	-	220	-	265	
,	STCP to Qn	C _L =50pF	4.5V	-	20	35	-	44	-	53	ns
	Seri	03001	6.0V	-	16	30	-	37	-	45	
t PHL		Figure 1	2.0V	-	47	175	-	220	-	265	
Propagation	MR to Q7S	CL=50pF	4.5V	-	17	35	-	44	-	53	ns
Delay		0L-00bi	6.0V	-	14	30	-	37	-	45	
		Figure 1	2.0V	-	47	150	-	190	-	225	
t _{EN} Enable Time	OE to Qn	Figure 1 C _L =50pF	4.5V	-	17	30	-	38	-	45	ns
		OL-SOPI	6.0V	-	14	26	-	33	-	38	
4		Figure 1	2.0V	-	41	150	-	190	-	225	
t _{DIS} Disable Time	OE to Qn	CL=50pF	4.5V	-	15	30	-	38	-	45	ns
		0[=300	6.0V	-	12	26	-	33	-	38	

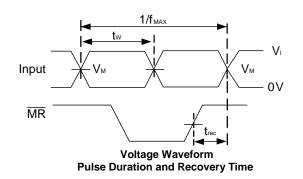


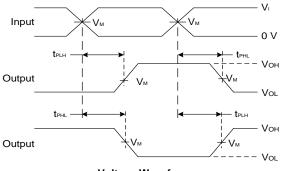
Parameter Measurement Information



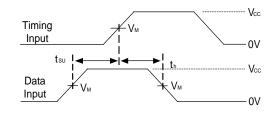
TEST	V _{LOAD}
t _{PLH} /t _{PHL}	Open
tpLZ/tpZL	Vcc
t _{PHZ} /t _{PZH}	GND

V _{cc}		Inputs	V _M	CL
	VI	t _r /t _f		
2.0V	V _{CC}	6ns	V _{CC} /2	50pF
4.5V	V _{CC}	6ns	V _{CC} /2	50pF
6.0V	V _{CC}	6ns	V _{CC} /2	50pF

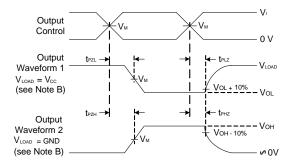




Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Set-up and Hold Times



Voltage Waveform Enable and Disable Times

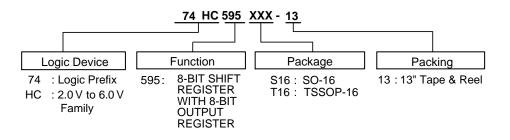
Notes: A. Includes test lead and test apparatus capacitance.

- B. Output Waveform 1 depends on the internal Q_N node being low and behaves in this manner based on OE pin. Output Waveform 2 depends on the internal Q_N node being high and behaves in this manner based on OE pin.
- C. All pulses are supplied at pulse repetition rate \leq 10MHz.
- D. Inputs are measured separately one transition per measurement.
- E. t_{PLH} and t_{PHL} are the same as t_{PD} .

Figure 1. Load Circuit and Voltage Waveforms



Ordering Information

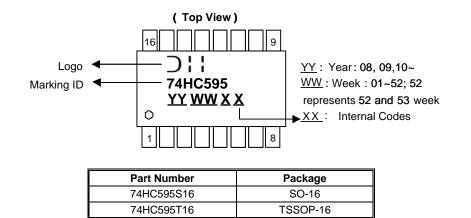


Part Number Package Co		Packaging	7" Tape and Reel (Note 6)		
Fait Nulliber	Package Code	Packaging	Quantity	Part Number Suffix	
74HC595S16-13	S16	SO-16	2500/Tape & Reel	-13	
74HC595T16-13	T16	TSSOP-16	2500/Tape & Reel	-13	

Note: 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

(1) SO-16, TSSOP16

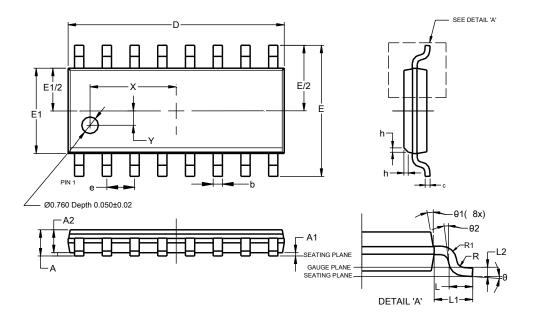




Package Outline Dimensions (All dimensions in mm.)

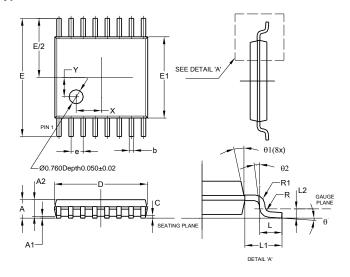
Please see http://www.diodes.com/package-outlines.html for the latest version.

Package Type: SO-16



	SO	-16						
Dim Min Max Typ								
Α		1.260						
A1	0.10	0.23						
A2	1.02							
b	0.31	0.51						
С	0.10	0.25						
D	9.80	10.00						
E	5.90	6.10						
E1	3.80	4.00						
е	1	.27 BS	С					
h	0.15	0.25	0.20					
L	0.40	1.27						
L1		.04 REF						
L2	C).25 BS(2					
R	0.07							
R1	0.07							
Х		945 RE						
Y	0	.661 RE	F					
θ	0°	8°						
θ1	5°	15°						
θ2	0°							
All	Dimens	ions in	mm					

Package Type: TSSOP-16



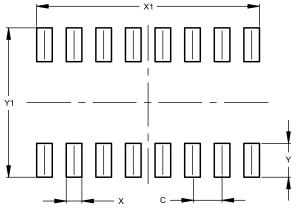
	TSSO	P-16				
Dim	Min Max Typ					
Α	-	1.08	-			
A1	0.05	0.15	-			
A2	0.80	0.93	-			
b	0.19	0.30	-			
С	0.09	0.20	-			
D	4.90	5.10	-			
E	6	6.40 BS	С			
E1	4.30	4.30 4.50 -				
е	().65 BS	С			
L		0.75	-			
L1		.00 RE				
L2	().25 BS	С			
R / R1	0.09	-	-			
Х	-	-	1.350			
Y	-	-	1.050			
θ	0°	8°	-			
θ1	5°	15°	-			
θ2	0°	-	-			
All Di	mensi	ons in	mm			



Suggested Pad Layout

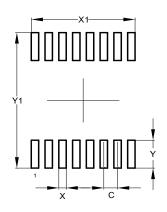
Please see http://www.diodes.com/package-outlines.html for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)
С	1.270
Х	0.670
X1	9.560
Y	1.450
Y1	6.400

Package Type: TSSOP-16



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	4.900
Y	1.400
Y1	6.800



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